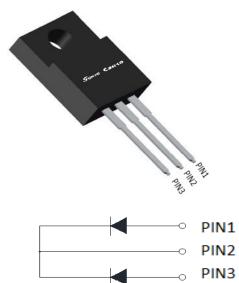


# **Schottky Diodes**



### **Features**

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

• Package: ITO-220AB

Molding compound meets UL 94 V-0 flammability

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102 • Polarity: As marked

# ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR2045FCTS
Device marking code			MBR2045FCTS
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, Tc=98°C	lo	А	20
Surge(Non-repetitive)Forward Current @60Hz half sine-wave,1 cycle, Ta=25°C	IFSM	Α	150
Current Squared Time @1ms≤t≤8.3ms Tj=25°C,	l²t	A²s	94
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ <b>+</b> 150
Junction Temperature	Tj	°C	-55 ~ <b>+</b> 150

## **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST	MBR2045FCTS
			CONDITIONS	
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A	0.65
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T <sub>a</sub> =25°C	0.2
	IRRM2		VRM=VRRM T <sub>a</sub> =125°C	50

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS



# ■Thermal Characteristics $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PARAMETER		SYMBOL	UNIT	MBR2045FCTS
Thermal Resistance	Between junction and case	R <sub>0</sub> J-C	°CW	4.0

## **■Ordering Information** (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR2045FCTS	Approximate 1.6	50	1000	5000	Tube

## **■Characteristics** (Typical)

FIG1:lo -Tc Curve

28.0
24.0
20.0
16.0
12.0
8.0
4.0
0
50
100
150

Case Temperature (°C)

FIG2:Surge Forward Current Capability

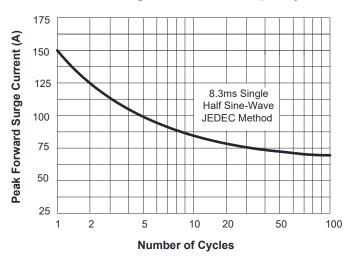


FIG3: Forward Voltage

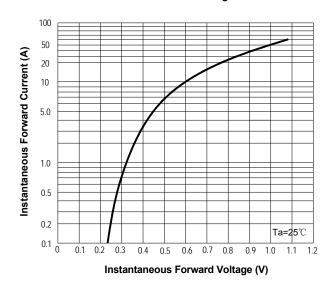
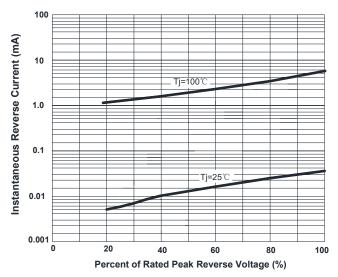
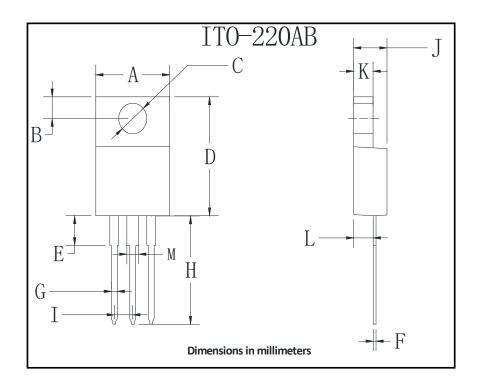


FIG.4: Typical Reverse Characteristics





## **■**Outline Dimensions



ITO-220AB				
Dim	Min	Max		
Α	9.8	10.2		
В	2.25	2.75		
С	2.95	3.45		
D	14.75	15.25		
E	3.05	3.95		
F	0.45	0.75		
G	0.45	0.75		
Н	13.4	14.2		
I	2.35	2.75		
J	4.3	4.8		
K	2.58	2.82		
L	2.58	2.82		
М	1.47	1.77		



#### **Disclaimer**

The information presented in this document is for reference only. Shanghai Sunco Electronics Co., Ltd reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Russiansunco or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website http:// <a href="http://www.russiansunco.com">www.russiansunco.com</a>, or consult your nearest Russiansunco's sales office for further assistance.